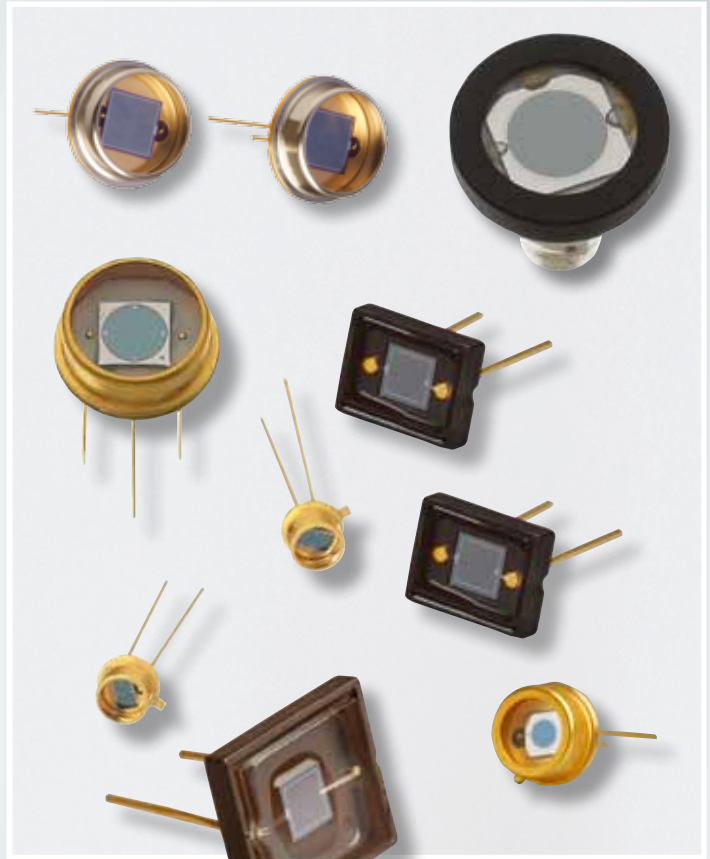


OSI Optoelectronics offers two distinct families of UV enhanced silicon photodiodes. Inversion channel series and planar diffused series. Both families of devices are especially designed for low noise detection in the UV region of electromagnetic spectrum.

Inversion layer structure UV enhanced photodiodes exhibit 100% internal quantum efficiency and are well suited for low intensity light measurements. They have high shunt resistance, low noise and high breakdown voltages. The response uniformity across the surface and quantum efficiency improves with 5 to 10 volts applied reverse bias. In photovoltaic mode (unbiased), the capacitance is higher than diffused devices but decreases rapidly with an applied reverse bias. Photocurrent non-linearity sets in at lower photocurrents for inversion layer devices compared to the diffused ones. Below 700nm, their responsivities vary little with temperature.

Planar diffused structure UV enhanced photodiodes show significant advantages over inversion layer devices, such as lower capacitance and higher response time. These devices exhibit linearity of photocurrent up to higher light input power compared to inversion layer devices. They have relatively lower responsivities and quantum efficiencies compared to inversion layer devices

There are two types of planar diffused UV enhanced photodiodes available: UVDQ and UVEQ. Both series have almost similar electro-optical characteristics, except in the UVEQ series, where the near IR responses of the devices are suppressed. This is especially desirable if blocking the near IR region of the spectrum is necessary. UVDQ devices peak at 970 nm and UVEQ devices at 720 nm (see graph). Both series may be biased for lower capacitance, faster response and wider dynamic range. Or they may be operated in the photovoltaic (unbiased) mode for applications requiring low drift with temperature variations. The UVEQ devices have a higher shunt resistance than their counterparts of UVDQ devices, but have a higher capacitance.



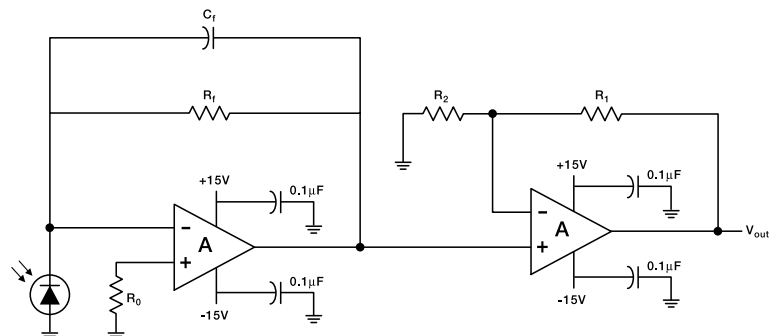
APPLICATIONS

- Pollution Monitoring
- Medical Instrumentation
- UV Exposure Meters
- Spectroscopy
- Water Purification
- Fluorescence

FEATURES

- Inversion series:
 - 100% Internal QE
- Ultra High R_{SH}
- Planar Diffused Series:
 - IR Suppressed
 - High Speed Response
 - High Stability
- Excellent UV response

These detectors are ideal for coupling to an OP-AMP in the current mode configuration as shown.



Inversion Layer UV Enhanced Photodiodes

Typical Electro-Optical Specifications at $T_A=23^\circ\text{C}$

Model Number	Active Area		Responsivity (A/W)		Capacitance (pF)	Shunt Resistance (M Ω)		NEP (W/ $\sqrt{\text{Hz}}$)	Reverse Voltage (V)	Rise Time (μs)	Operating Current (mA)	Temp.* Range ($^\circ\text{C}$)		Package Style ¶
	Area (mm 2)	Dimensions (mm)	254 nm		0 V	-10 mV		0V 254 nm		0 V 254 nm 50 Ω	0 V	Operating	Storage	
			min.	typ.	max.	min.	typ.	typ.		max.	typ.			

'UV Enhanced' Series, Inversion Layer, Metal Package

UV-001 «	0.8	1.0 ϕ	0.09	0.14	60	250	500	6.4 e-14	5	0.2	0.1	-20 ~ +60	-55 ~ +80	5 / TO-5	
UV-005	5.1	2.54 ϕ			300	80	200	1.0 e-13		0.9					
UV-015	15	3.05 x 3.81			800	30	100	1.4 e-13		2.0					
UV-20	20	5.08 ϕ			1000	25	50	2.0 e-13		2.0					
UV-35	35	6.60 x 5.33			1600	20	30	1.7 e-13		3.0				6 / TO-8	
UV-50	50	7.87 ϕ			2500	10	20	2.6 e-13		3.5					11 / BNC
UV-50L ‡															
UV-100	100	11.28 ϕ			4500	5	10	4.5 e-13		5.9					11 / BNC
UV-100L			10 / Lo-Prof												

'UV Enhanced' Series, Inversion Layer, Plastic Package §

UV-35P	35	6.60 x 5.33	0.09	0.14	1600	15	30	1.7 e-13	5	3.0	0.1	-10 ~ +60	-20 ~ +70	25 / Plastic
FIL-UV50	50	7.87 ϕ			2500	10	20	2.1 e-13		3.5				15 / Plastic

‡ The 'L' suffix on the model number is indicative of the photodiode chip being isolated from the package by an additional pin connected to the case.

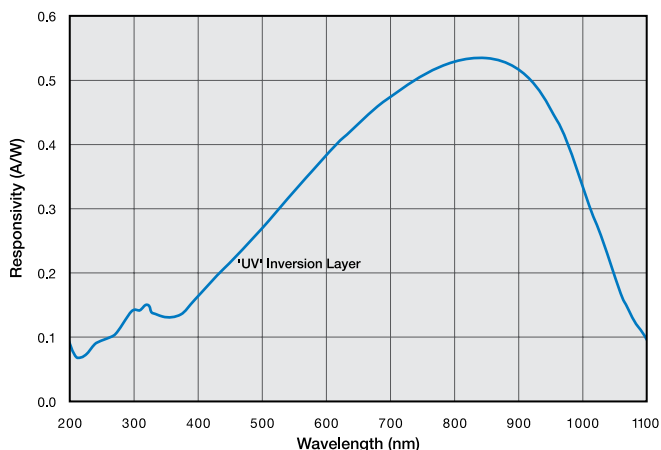
§ The photodiode chips in "FIL" series are isolated in a low profile plastic package. They have a large field of view as well as in line pins.

¶ For mechanical drawings please refer to pages 61 thru 73.

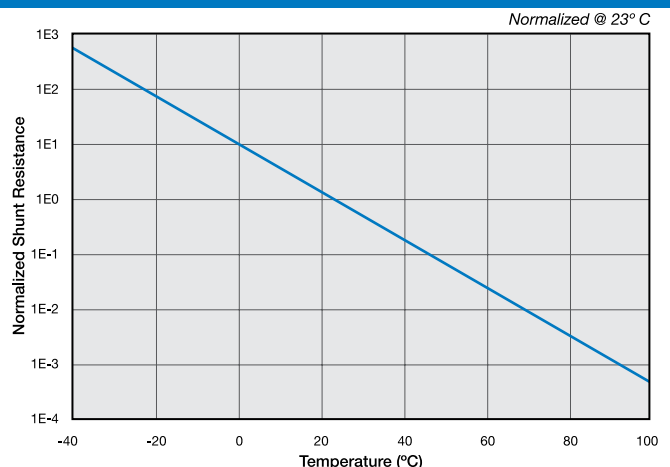
* Non-Condensing temperature and Storage Range, Non-Condensing Environment.

« Minimum order quantities apply

Typical Spectral Response



Typical Shunt Resistance vs. Temperature



AVOID DIRECT LIGHT

Since the spectral response of silicon photodiode includes the visible light region, care must be taken to avoid photodiode exposure to high ambient light levels, particularly from tungsten sources or sunlight. During shipment from OSI Optoelectronics, your photodiodes are packaged in opaque, padded containers to avoid ambient light exposure and damage due to shock from dropping or jarring.

AVOID SHARP PHYSICAL SHOCK

Photodiodes can be rendered inoperable if dropped or sharply jarred. The wire bonds are delicate and can become separated from the photodiode's bonding pads when the detector is dropped or otherwise receives a sharp physical blow.

CLEAN WINDOWS WITH OPTICAL GRADE CLOTH / TISSUE

Most windows on OSI Optoelectronics photodiodes are either silicon or quartz. They should be cleaned with isopropyl alcohol and a soft (optical grade) pad.

OBSERVE STORAGE TEMPERATURES AND HUMIDITY LEVELS

Photodiode exposure to extreme high or low storage temperatures can affect the subsequent performance of a silicon photodiode. Storage temperature guidelines are presented in the photodiode performance specifications of this catalog. Please maintain a non-condensing environment for optimum performance and lifetime.

OBSERVE ELECTROSTATIC DISCHARGE (ESD) PRECAUTIONS

OSI Optoelectronics photodiodes, especially with IC devices (e.g. Photops) are considered ESD sensitive. The photodiodes are shipped in ESD protective packaging. When unpacking and using these products, anti-ESD precautions should be observed.

DO NOT EXPOSE PHOTODIODES TO HARSH CHEMICALS

Photodiode packages and/or operation may be impaired if exposed to CHLOROTHENE, THINNER, ACETONE, or TRICHLOROETHYLENE.

INSTALL WITH CARE

Most photodiodes in this catalog are provided with wire or pin leads for installation in circuit boards or sockets. Observe the soldering temperatures and conditions specified below:

Soldering Iron:	Soldering 30 W or less Temperature at tip of iron 300°C or lower.
Dip Soldering:	Bath Temperature: 260±5°C. Immersion Time: within 5 Sec. Soldering Time: within 3 Sec.
Vapor Phase Soldering:	DO NOT USE
Reflow Soldering:	DO NOT USE

Photodiodes in plastic packages should be given special care. Clear plastic packages are more sensitive to environmental stress than those of black plastic. Storing devices in high humidity can present problems when soldering. Since the rapid heating during soldering stresses the wire bonds and can cause wire to bonding pad separation, it is recommended that devices in plastic packages to be baked for 24 hours at 85°C.

The leads on the photodiode **SHOULD NOT BE FORMED**. If your application requires lead spacing modification, please contact OSI Optoelectronics Applications group at (310)978-0516 before forming a product's leads. Product warranties could be voided.



*Most of our standard catalog products are RoHS Compliant. Please contact us for details

Mechanical Drawings

Mechanical Specifications and Die Topography

1. Parameter Definitions:

A = Distance from top of chip to top of glass.

a = Photodiode Anode.

B = Distance from top of glass to bottom of case.

c = Photodiode Cathode

(Note: cathode is common to case in metal package products unless otherwise noted).

W = Window Diameter.

F.O.V. = Filed of View (see definition below).

2. Dimensions are in inches (1 inch = 25.4 mm).

3. Pin diameters are 0.018 ± 0.002 " unless otherwise specified.

4. Tolerances (unless otherwise noted)

General: $0.XX \pm 0.01$ "

$0.XXX \pm 0.005$ "

Chip Centering: ± 0.010 "

Dimension 'A': ± 0.015 "

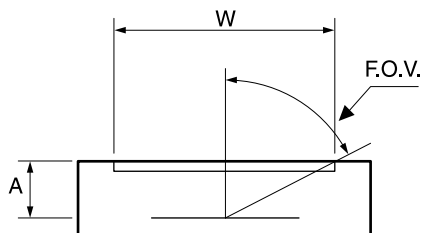
5. Windows

All '**UV**' Enhanced products are provided with QUARTZ glass windows, 0.027 ± 0.002 " thick.

All '**XUV**' products are provided with removable windows.

All '**DLS**' PSD products are provided with A/R coated glass windows.

All '**FIL**' photoconductive and photovoltaic products are epoxy filled instead of glass windows.



$$F.O.V. = \tan^{-1} \left(\frac{W}{2A} \right)$$

For Further Assistance
Please Call One of Our Experienced
Sales and Applications Engineers

310-978-0516

OSI Optoelectronics
An OSI Systems Company

- Or -

visit our website at

www.osioptoelectronics.com

Mechanical Specifications

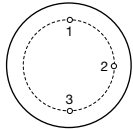
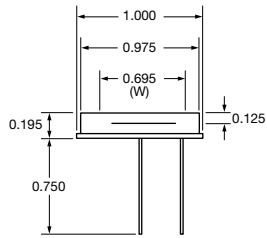
All units in inches. Pinouts are bottom view.

1 TO-18	2 TO-5	3 TO-8																																	
<p>Products: PIN-020A PIN-040A PIN-040-DP/SB</p> <p>Pin Circle Dia.=0.100</p> <table border="1"> <thead> <tr> <th>P/N</th> <th>A</th> <th>B</th> <th>W</th> </tr> </thead> <tbody> <tr> <td>PIN-020A</td> <td>0.075</td> <td>0.200</td> <td>0.155</td> </tr> <tr> <td>PIN-040A</td> <td>0.075</td> <td>0.200</td> <td>0.155</td> </tr> </tbody> </table>	P/N	A	B	W	PIN-020A	0.075	0.200	0.155	PIN-040A	0.075	0.200	0.155	<p>Products: PIN-5DI PIN-5DPI PIN-13DI PIN-13DPI PIN-5-YAG CD-25T</p> <p>Pin Circle Dia.=0.200</p> <table border="1"> <thead> <tr> <th>P/N</th> <th>A</th> <th>B</th> <th>W</th> </tr> </thead> <tbody> <tr> <td>All Others</td> <td>0.094</td> <td>0.180</td> <td>0.240</td> </tr> <tr> <td>CD-25T</td> <td>0.050</td> <td>0.130</td> <td>0.23</td> </tr> </tbody> </table>	P/N	A	B	W	All Others	0.094	0.180	0.240	CD-25T	0.050	0.130	0.23	<p>Products: PIN-6DI PIN-6DPI PIN-44DI PIN-44DPI APD50-8-150-TO8</p> <p>Pin Circle Dia.=0.295</p> <table border="1"> <thead> <tr> <th>P/N</th> <th>A</th> </tr> </thead> <tbody> <tr> <td>PIN-6DI/6DPI APD50-8-150-TO8</td> <td>0.115</td> </tr> <tr> <td>PIN-44DI/44DPI</td> <td>0.125</td> </tr> <tr> <td>OSD35-0</td> <td>0.130</td> </tr> </tbody> </table>	P/N	A	PIN-6DI/6DPI APD50-8-150-TO8	0.115	PIN-44DI/44DPI	0.125	OSD35-0	0.130	
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<p>Products: PIN-2DI PIN-2DPI PIN-3CDI PIN-3CDP PIN-3CDPI</p> <p>Pin Circle Dia.=0.100</p> <table border="1"> <thead> <tr> <th>A</th> <th>B</th> </tr> </thead> <tbody> <tr> <td>0.070</td> <td>0.200</td> </tr> <tr> <td>0.090</td> <td>0.150</td> </tr> </tbody> </table>	A	B	0.070	0.200	0.090	0.150	<p>Products: PIN-5D PIN-5DP PIN-5DP/SB PIN-13D PIN-13DP PIN-005E-550F UV-001 UV-005 UV-005DQ UV-005EQ UV-013DQ UV-013EQ UV-015 OSD-5-0 OSD15-0 OSD5-5T OSD15-5T</p> <p>Pin Circle Dia.=0.200</p> <table border="1"> <thead> <tr> <th>P/N</th> <th>A</th> <th>B</th> </tr> </thead> <tbody> <tr> <td>OSD-Prefix Devices</td> <td>0.050</td> <td>0.130</td> </tr> <tr> <td>UV-XXXDQ</td> <td>0.065</td> <td>0.138</td> </tr> <tr> <td>UV-XXXEQ</td> <td>0.055</td> <td>0.138</td> </tr> <tr> <td>All Others</td> <td>0.102</td> <td>0.180</td> </tr> </tbody> </table> <p>Quartz Window: OSD5.8-7Q UV Transmissive Window: OSD5.8-7U</p>	P/N	A	B	OSD-Prefix Devices	0.050	0.130	UV-XXXDQ	0.065	0.138	UV-XXXEQ	0.055	0.138	All Others	0.102	0.180	<p>Products: PIN-6D PIN-6DP PIN-44D PIN-44DP UV-020 UV-035DQ UV-035EQ UV-035 Dimensions</p> <p>Pin Circle Dia.=0.295</p> <table border="1"> <thead> <tr> <th>P/N</th> <th>A</th> <th>B</th> </tr> </thead> <tbody> <tr> <td>UV-035DQ</td> <td>0.130</td> <td>0.195</td> </tr> <tr> <td>UV-035EQ</td> <td>0.120</td> <td>0.195</td> </tr> <tr> <td>All Others</td> <td>0.140</td> <td>0.205</td> </tr> </tbody> </table>	P/N	A	B	UV-035DQ	0.130	0.195	UV-035EQ	0.120	0.195	All Others	0.140	0.205
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<p>Products: PIN-3CD PIN-3CDP BPX-65 OSD1-0 OSD1-5T OSD3-5T OSD1-E OSD3-E</p> <p>Pin Circle Dia.=0.100</p> <table border="1"> <thead> <tr> <th>P/N</th> <th>A</th> <th>B</th> </tr> </thead> <tbody> <tr> <td>PIN-3CD / 3CDP</td> <td>0.087</td> <td>0.146</td> </tr> <tr> <td>BPX-65</td> <td>0.075</td> <td>0.200</td> </tr> <tr> <td>OSD-Prefix Devices</td> <td>0.080</td> <td>0.200</td> </tr> </tbody> </table> <p>Quartz Window: OSD1.2-7Q UV Transmissive Window: OSD1.2-7U</p>	P/N	A	B	PIN-3CD / 3CDP	0.087	0.146	BPX-65	0.075	0.200	OSD-Prefix Devices	0.080	0.200	<p>Products: PIN-125DPL</p> <p>Pin Circle Dia.=0.100</p>	<p>Products: PIN-HR005 PIN-HR008 PIN-HR020 PIN-HR026 PIN-HR040</p> <p>Pin Circle Dia.=0.100</p>																					
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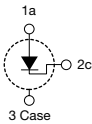
Mechanical Specifications

All units in inches. Pinouts are bottom view.

10 Low Profile



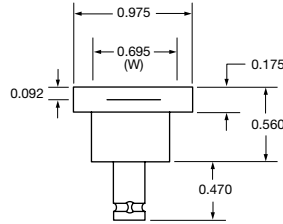
Pin Circle Dia.=0.73



Products:

PIN-10DI
PIN-10DPI
PIN-10DPI/SB
UV-50L
UV-100L

11 BNC

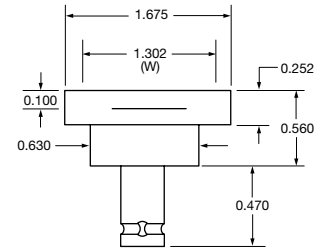


Outer Contact — Anode	PIN-10D, PIN-10DP, PIN-10DP/SB UV-100DQ, UV-100EQ
Outer Contact — Cathode	UV-50, UV-100

Products:

PIN-10D
PIN-10DP
PIN-10DP/SB
UV-50
UV-100
UV-100DQ
UV-100EQ

12 BNC

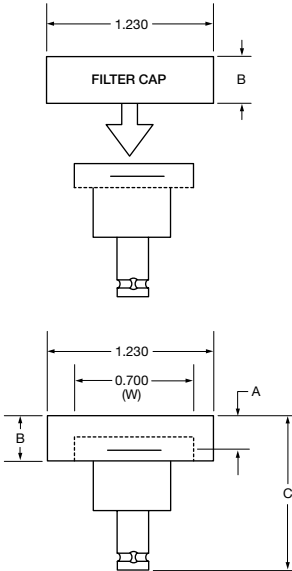


Outer Contact — Anode

Products:

PIN-25D
PIN-25DP

13 Special BNC

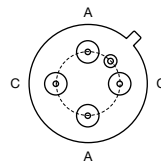
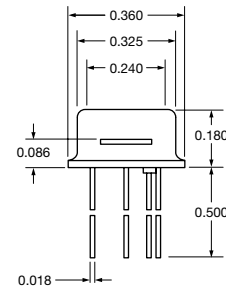


Dimensions			
P/N	A	B	C
PIN-10DF	0.217	0.330	1.020
PIN-10AP	0.386	0.550	1.415

Products:

PIN-10AP
PIN-10DF

14 TO-5

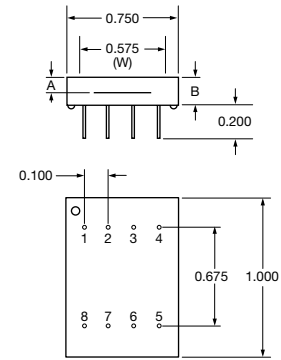


Pin Circle Dia.= 0.200
Bottom View

Products:

DLS-2S

15 Special Plastic



Dimensions

P/N	A	B
FIL-UV50	0.090	0.155

Pinouts

P/N	1	2	3	4	5	6	7	8
FIL-UV50	c	-	-	a	c	-	-	a

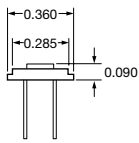
Mechanical Specifications

All units in inches. Pinouts are bottom view.

22 TO-5

Products:

XUV-005



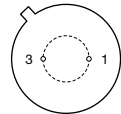
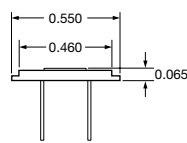
Pin Circle Dia.=0.200



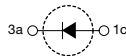
23 TO-8

Products:

XUV-020
XUV-035



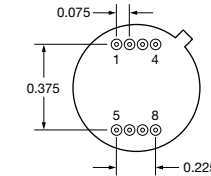
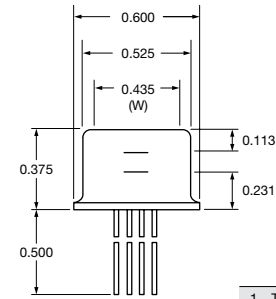
Pin Circle Dia.=0.295



24 TO-8

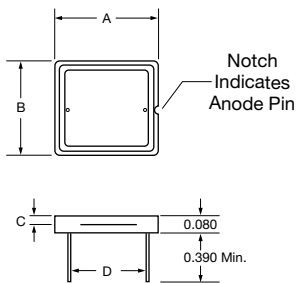
Products:

PIN-DSIn-TEC



Pinout	
1	TEC (-)
2	Thermistor
3	Thermistor
4	TEC (+)
5	Top Silicon, Cathode
6	Top Silicon, Anode
7	Bottom InGaAs, Anode
8	Bottom InGaAs, Cathode

25 Special Ceramic / Plastic



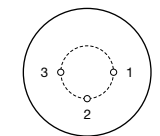
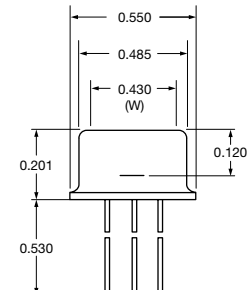
P/N	Dimensions			
	A	B	C	D
UV-005EQC	0.300	0.236	0.024	0.177
UV-035EQC	0.400	0.350	0.028	0.290
UV-100EQC	0.650	0.590	0.028	0.490
UV-005DQC	0.300	0.236	0.035	0.177
UV-035DQC	0.400	0.350	0.039	0.290
UV-100DQC	0.650	0.590	0.039	0.490
XUV-50C	0.650	0.590	0.027	0.490
XUV-100C	0.650	0.590	0.027	0.490
RD-100	0.650	0.590	0.027	0.490
RD-100A	0.650	0.590	0.027	0.490
UV-35P	0.390	0.345	0.050	0.275
OSD35-LR-A	0.390	0.350	---	0.290
OSD35-LR-D	0.390	0.350	---	0.290

Note: OSD35-prefix packages come with 0.31" (min.) leads

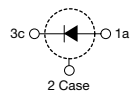
26 TO-8

Products:

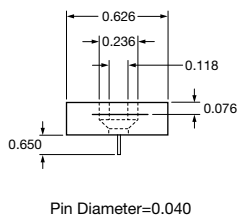
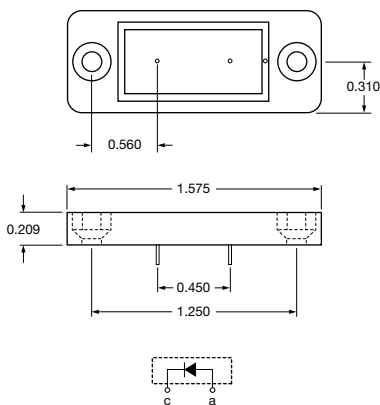
RD-100
RD-100A
UV-35P
UV-005EQC
UV-035EQC
UV-100EQC
UV-005DQC
UV-035DQC
UV-100DQC
XUV-50C
XUV-100C
OSD35-LR-A
OSD35-LR-D



Pin Circle Dia.=0.295



27 Special Plastic



Pin Diameter=0.040



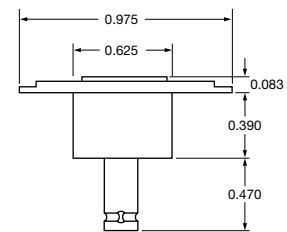
28 BNC

Products:

PIN-220D
PIN-220DP
PIN-220DP/SB

Products:

XUV-100



BNC Connector
Outer Contact = Cathode